

# Phonon-Mediated Distributed Transition- Edge-Sensor X-ray Detectors

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# Overview

- **Goals, applications and detector basics**
- Energy systems, charge traps and neutralization
- 2-d Si
- 2-d Ge
- 2-d Si with deep trenches
- Energy Resolution

# Performance Goals

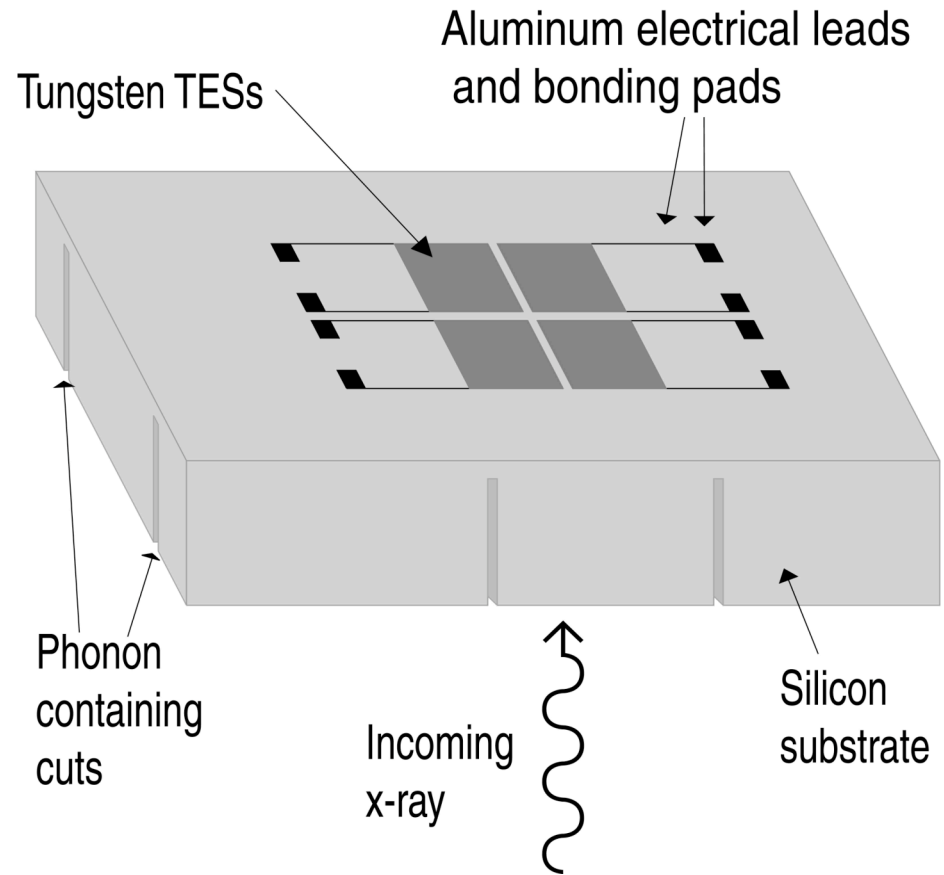
- 2 dimension resolving.
- 1-10 keV band.
- Position resolution  $x/\delta x$  and  $y/\delta y \sim 100$ .
- Energy resolution  $E/\delta E \sim 1000$ .
  
- Eventually multiplexed into 30 x 30 arrays.
- Equivalent to a 10 megapixel device.

# Applications

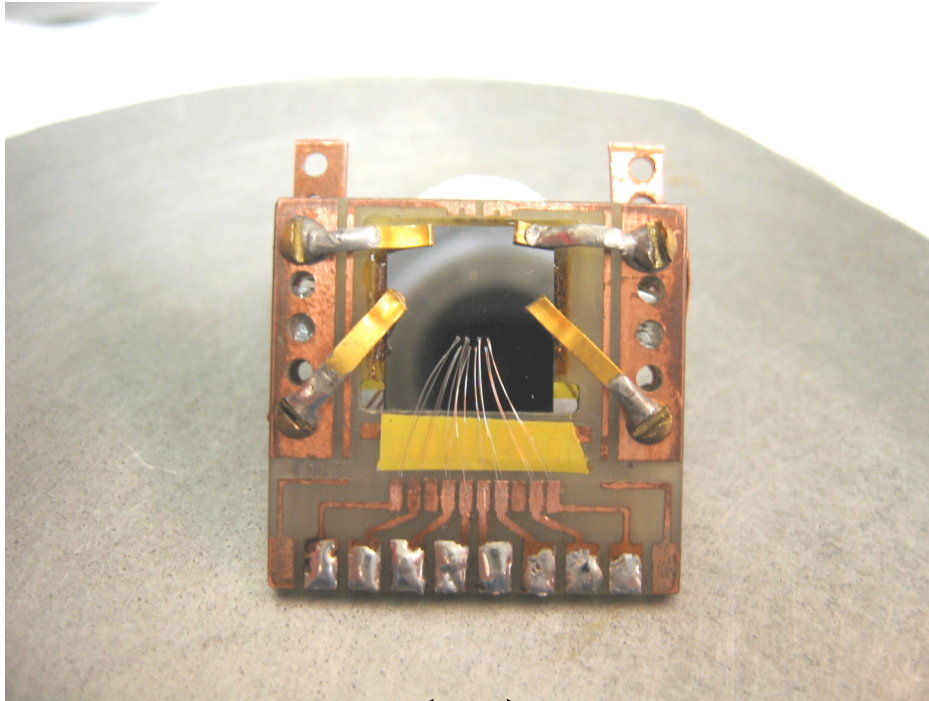
- Large area, time resolution, energy resolution and position resolution, dead time...
- Astrophysical studies such as...
- Magnetic recombination in the solar corona.
- Warm-hot intergalactic medium
- Surveys of clusters and groups of galaxies.
- These have been suggested by Blas Cabrera, Steven Kahn, Bob Stern, Steve Deiker and others.

# 2x2 Detector

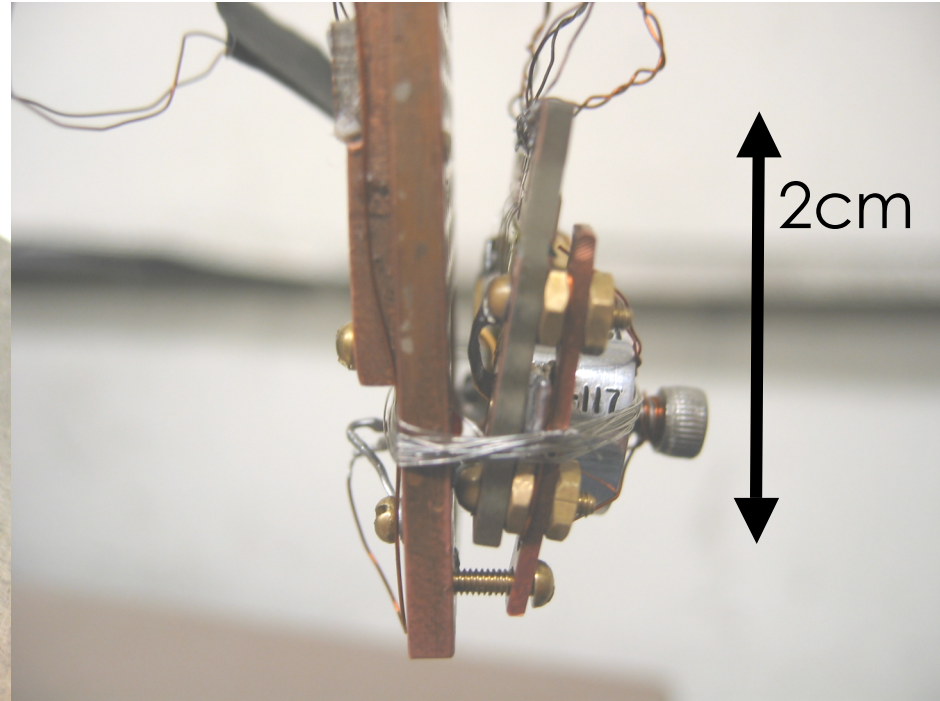
- Position cuts in 2 directions.
- Third dimension not resolvable.
- The four TESs cover a region  $500\mu\text{m} \times 500\mu\text{m}$ .
- The crystal is  $350\mu\text{m}$  thick.
- The trenches are  $\sim 220\mu\text{m}$  deep.



# Detector with Source



1 cm

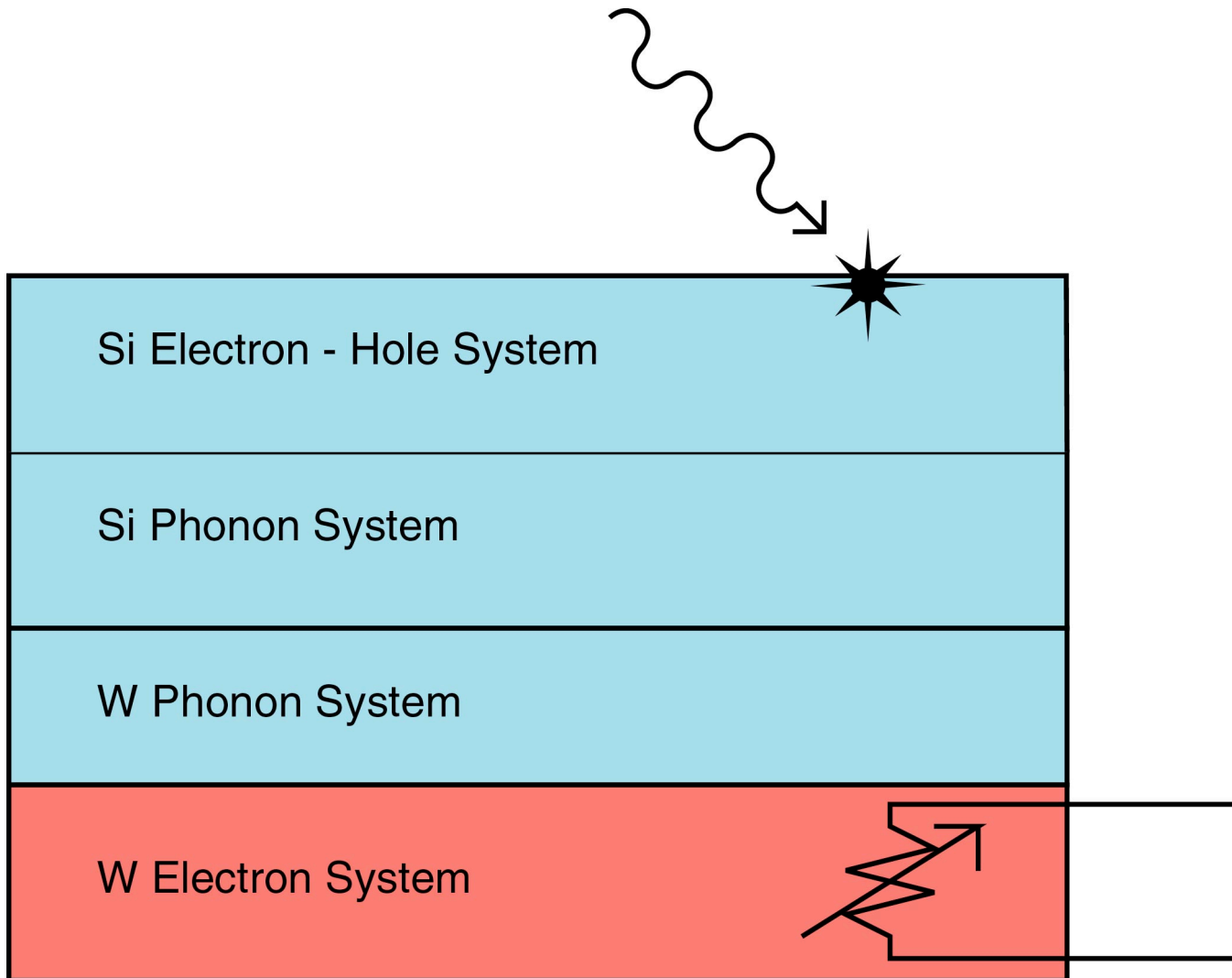


2 cm

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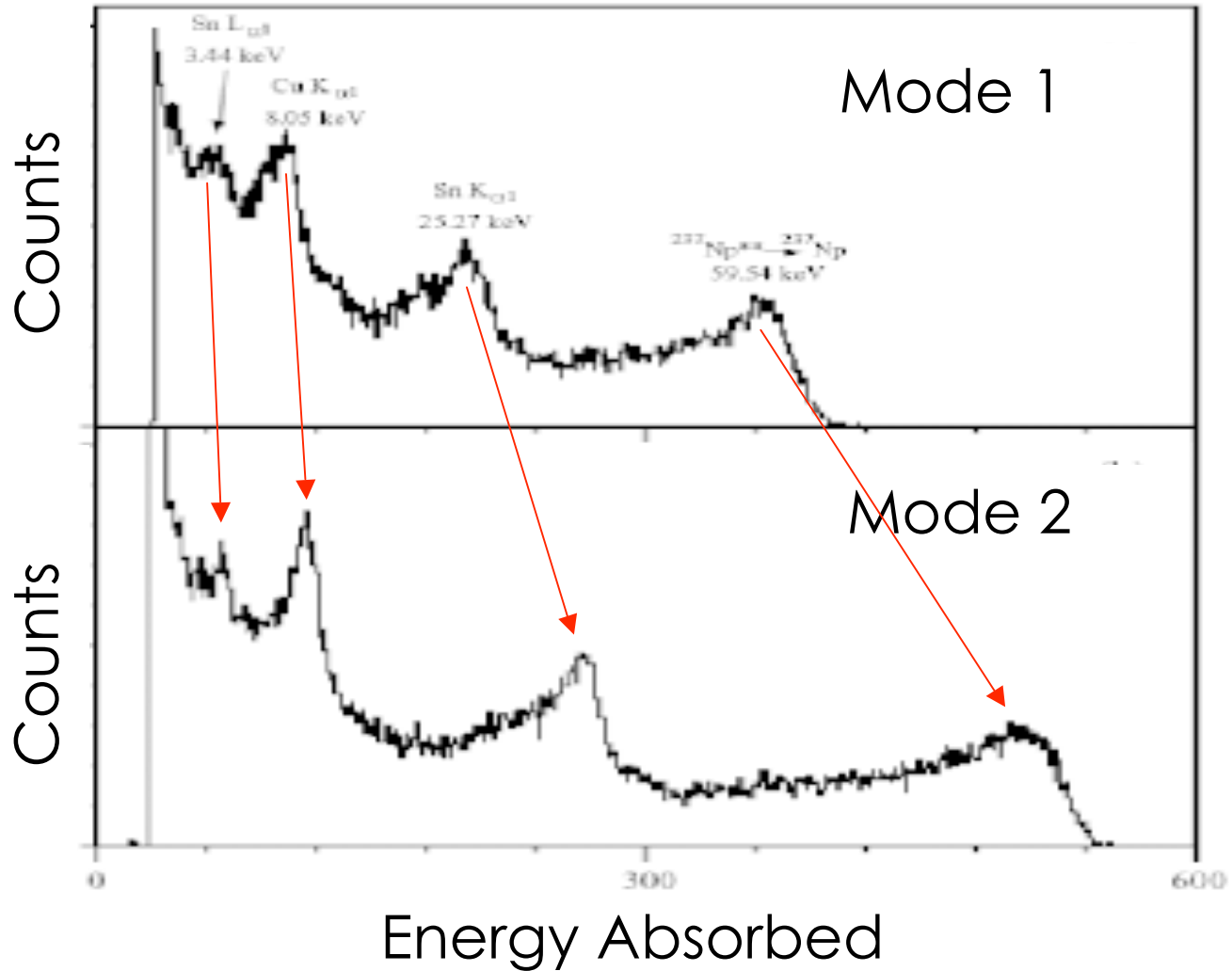
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# Energy Systems

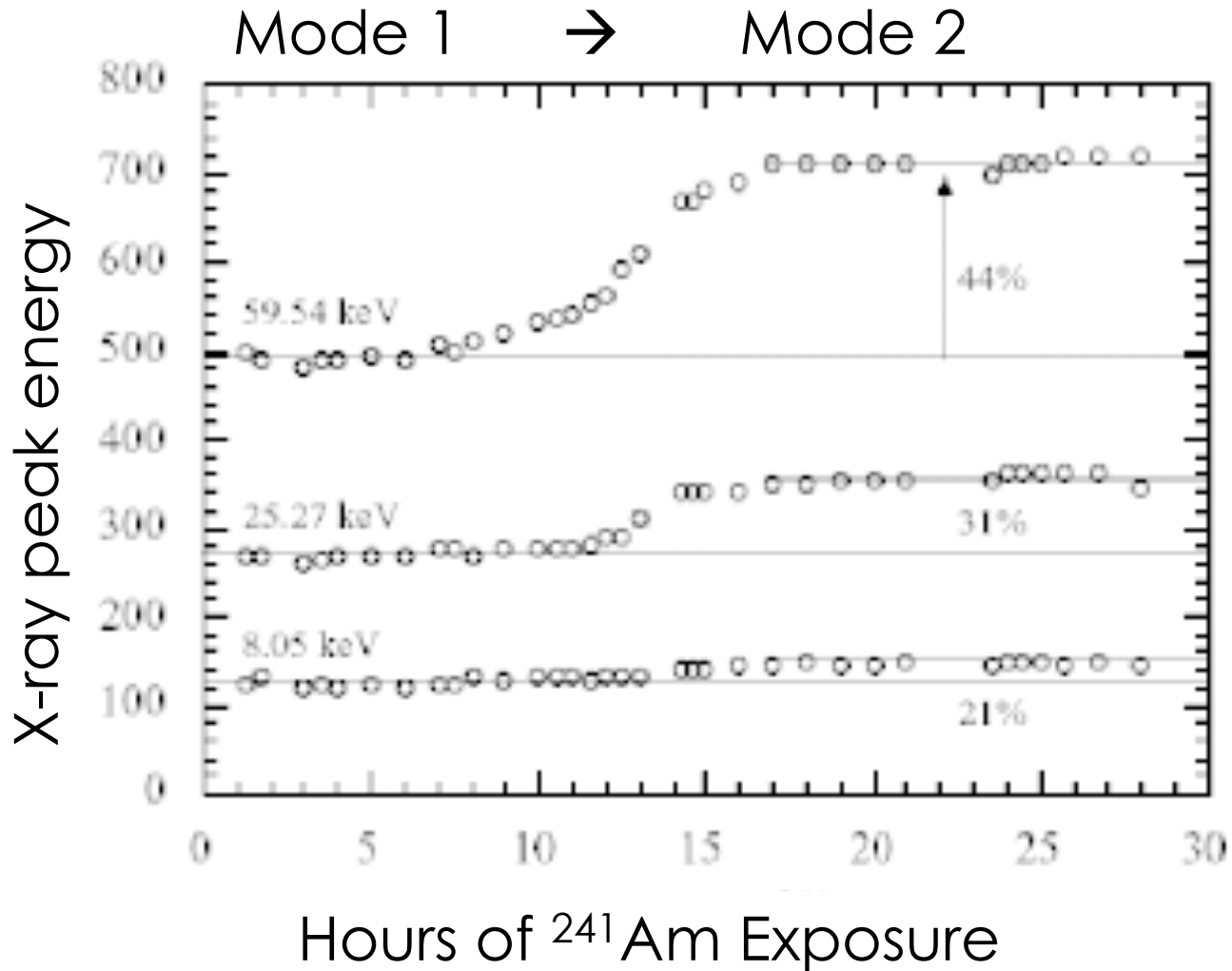




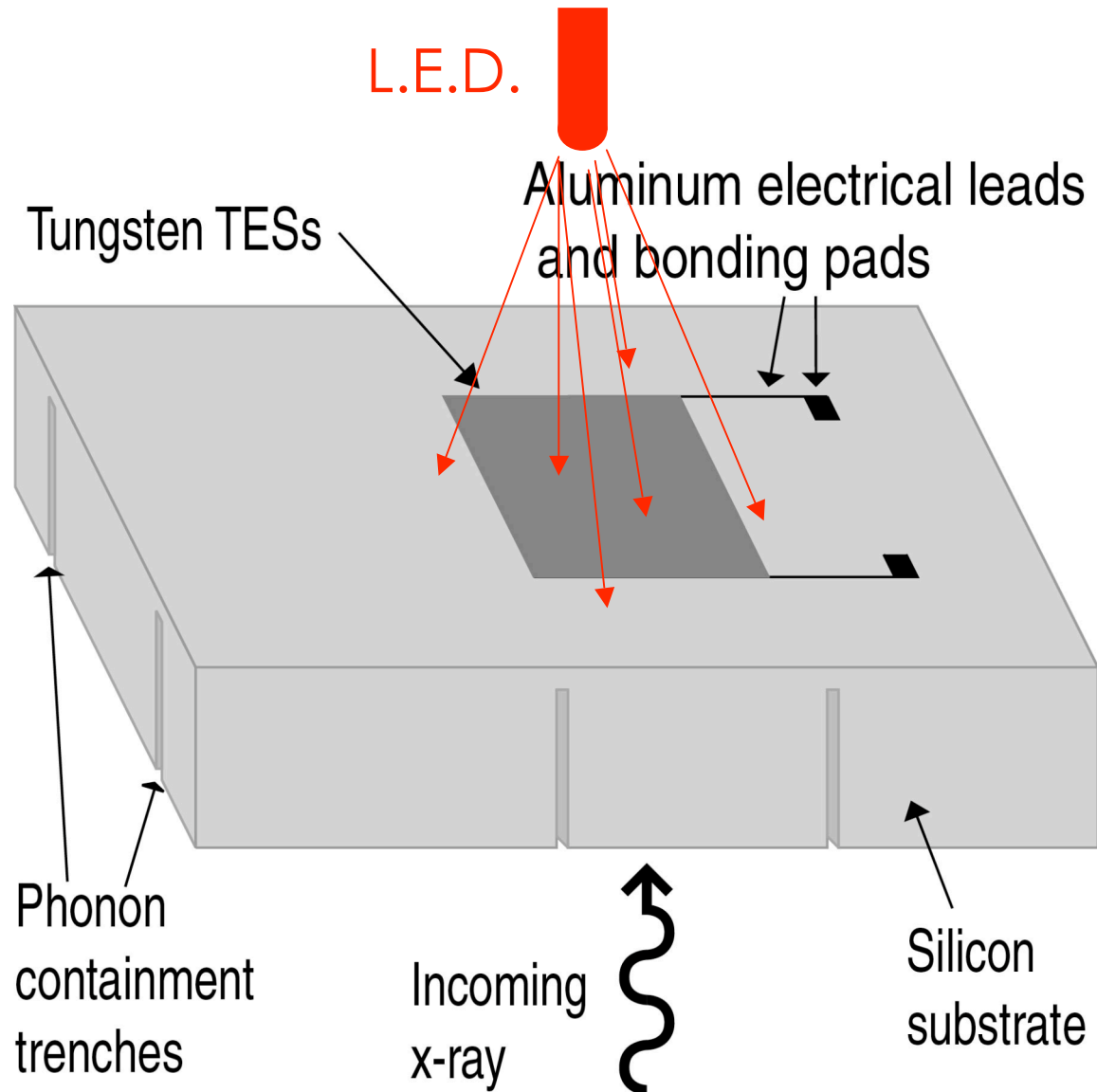
# Charge Traps



# Neutralization Completion



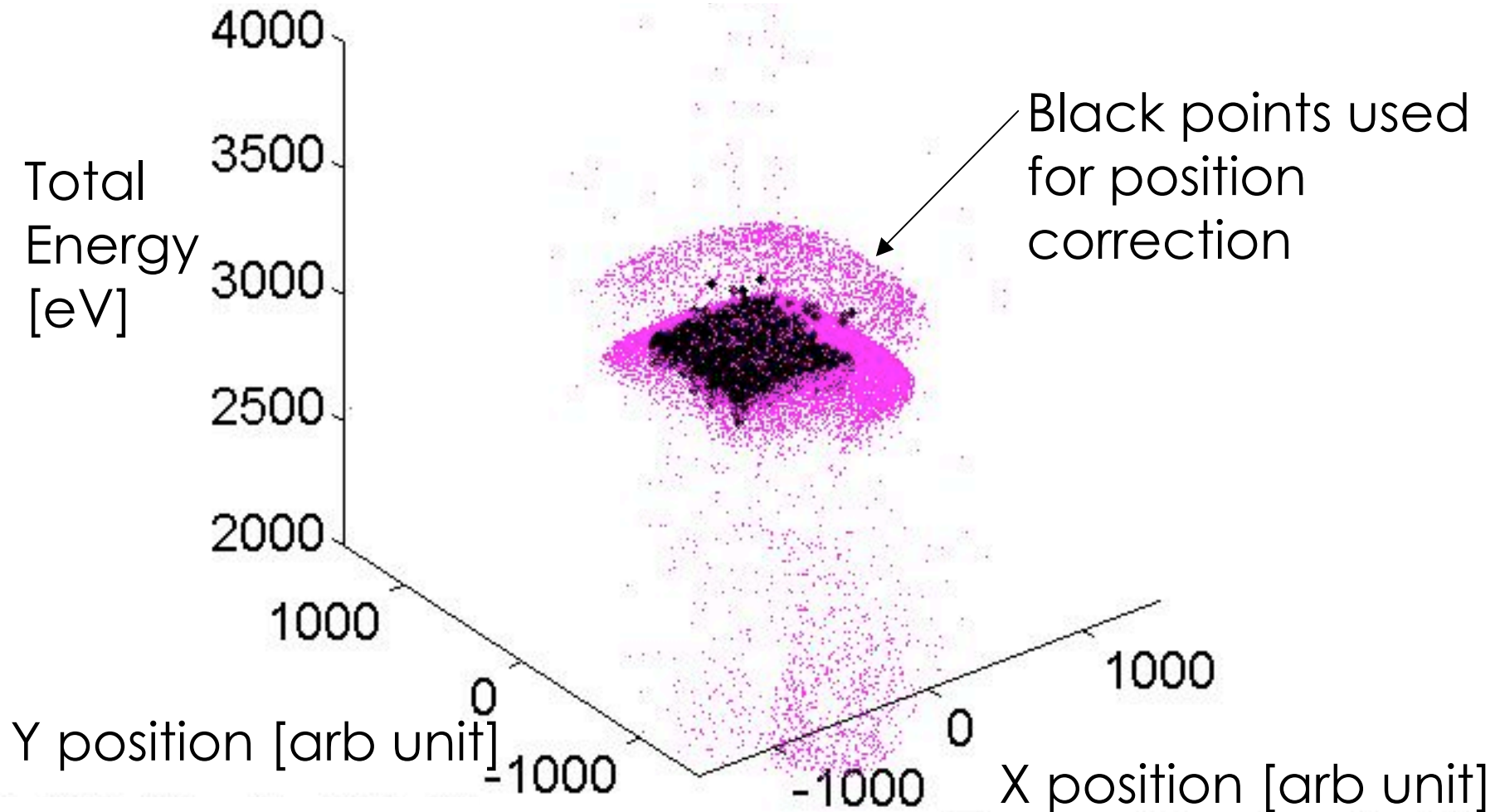
# Crystal Neutralization



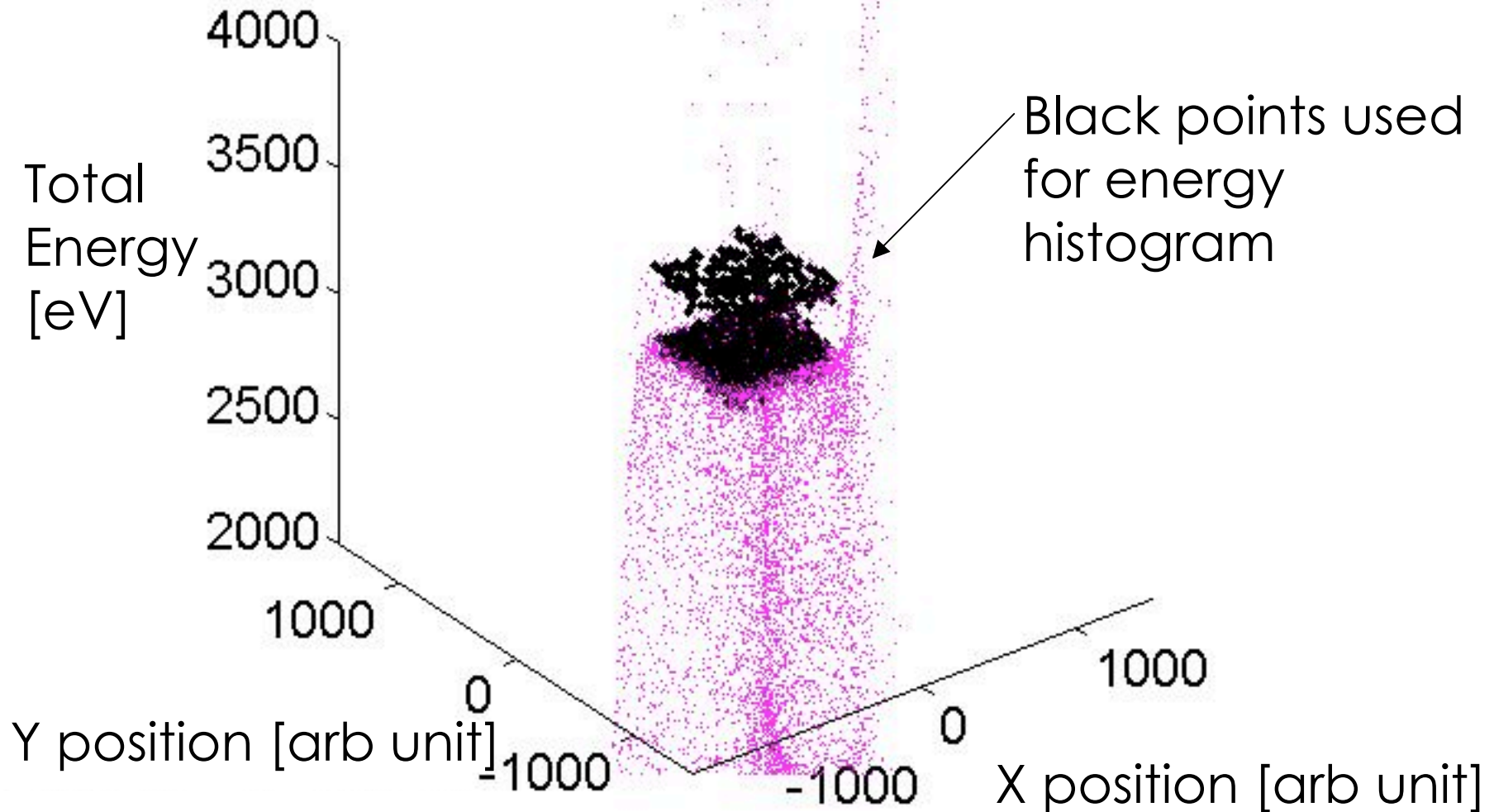
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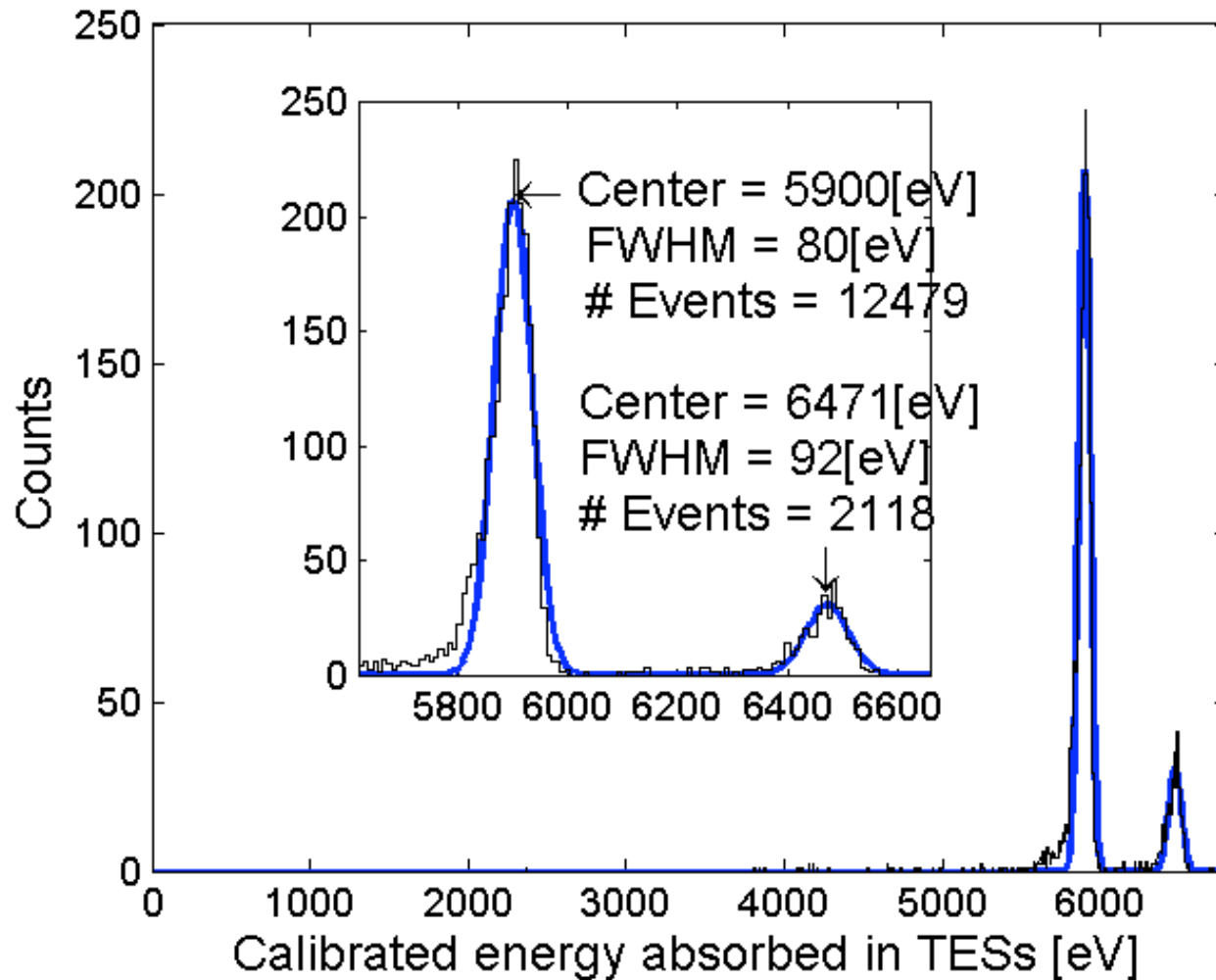
# Energy Partitioning



# Energy Partitioning



# Spectra



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# Energy Losses

- Energy resolution is degraded due to energy going into nondetectable channels.
  - Electron—hole pairs lost in charge traps.
  - Electron—hole pairs diffuse through bridge and lost to the environment.
  - Phonons escape through bridge and lost to the environment.

# Germanium Absorbers

- Want pure Ge absorbers (less charge traps).
- First use cheaper doped Ge absorbers.
- Problems...
  - Xtal thicker.
  - Bridges thicker (Very conservative trenching since Ge is more fragile).
  - Debye frequency  $\sim 1/2$  of Si's (coupling to W  $\sim$  frequency).

# Germanium Detector

- These problems led to a reduction in the amount of energy absorbed in the TESs ( $\sim 500\text{eV}$ ).
  - Actually, only 3 TESs were working and the  $500\text{eV}$  amount is what would be expected in four working TESs.
  - This is consistent with simulation indicating that the simulation's parameters are not far off.
- An actual line width was not determined.

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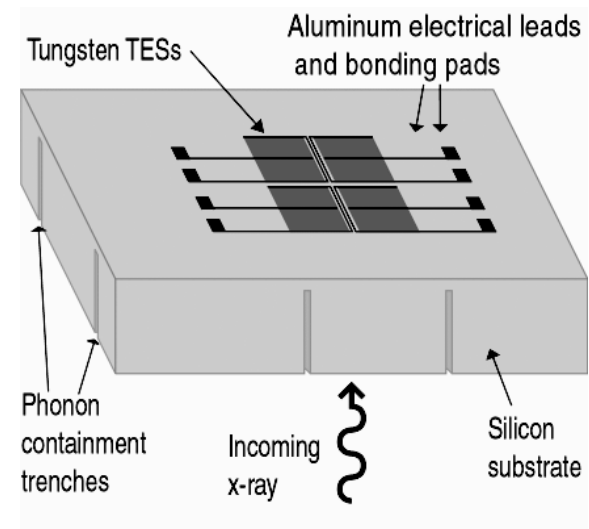
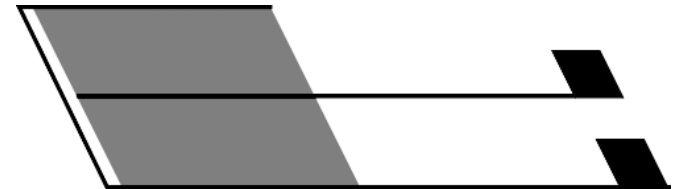
# 2-d Si Detector with ``split'' TESs and deep trenches

- Deeper trenches to reduce phonon and charge losses through the connecting bridge.
- The trenches are  $320\mu\text{m}$  deep, 90% of crystal thickness.
- ~70% of the initial x-ray energy was read out by the TESs.
- Considering the  $220\mu\text{m}$  deep trenches and  $320\mu\text{m}$  deep trenches absorption of 49 & 70% respectively, a total of 76% absorbed in completely trenched detector.

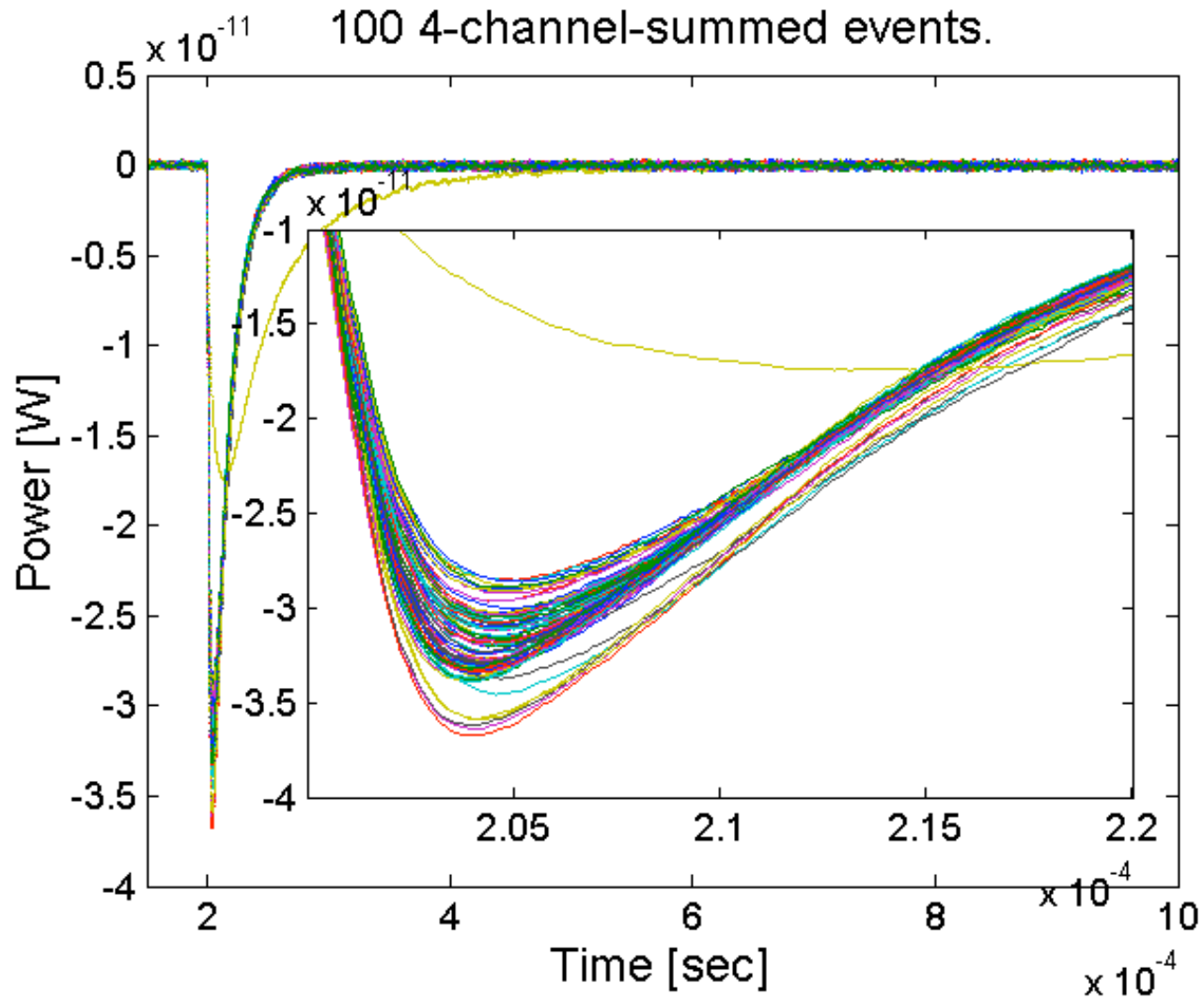
# Split TESs

- Split TESs suppress / reduce phase separation in the current flowing direction.

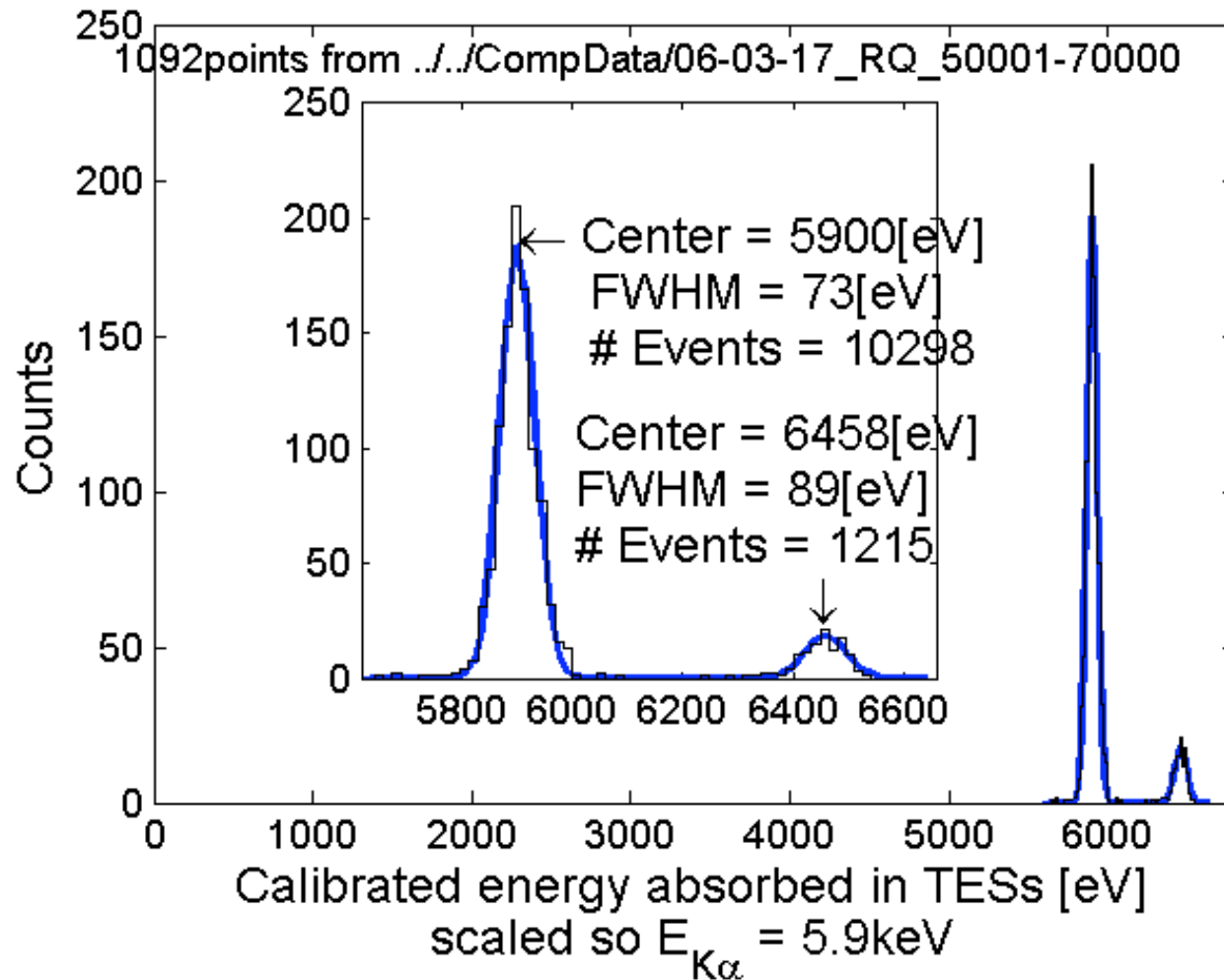
$$I_{\max}^2 = \pi^2 L_{Lor} / \alpha \Sigma T_c^3 \rho_n$$



# Band Mixing



# After Cuts

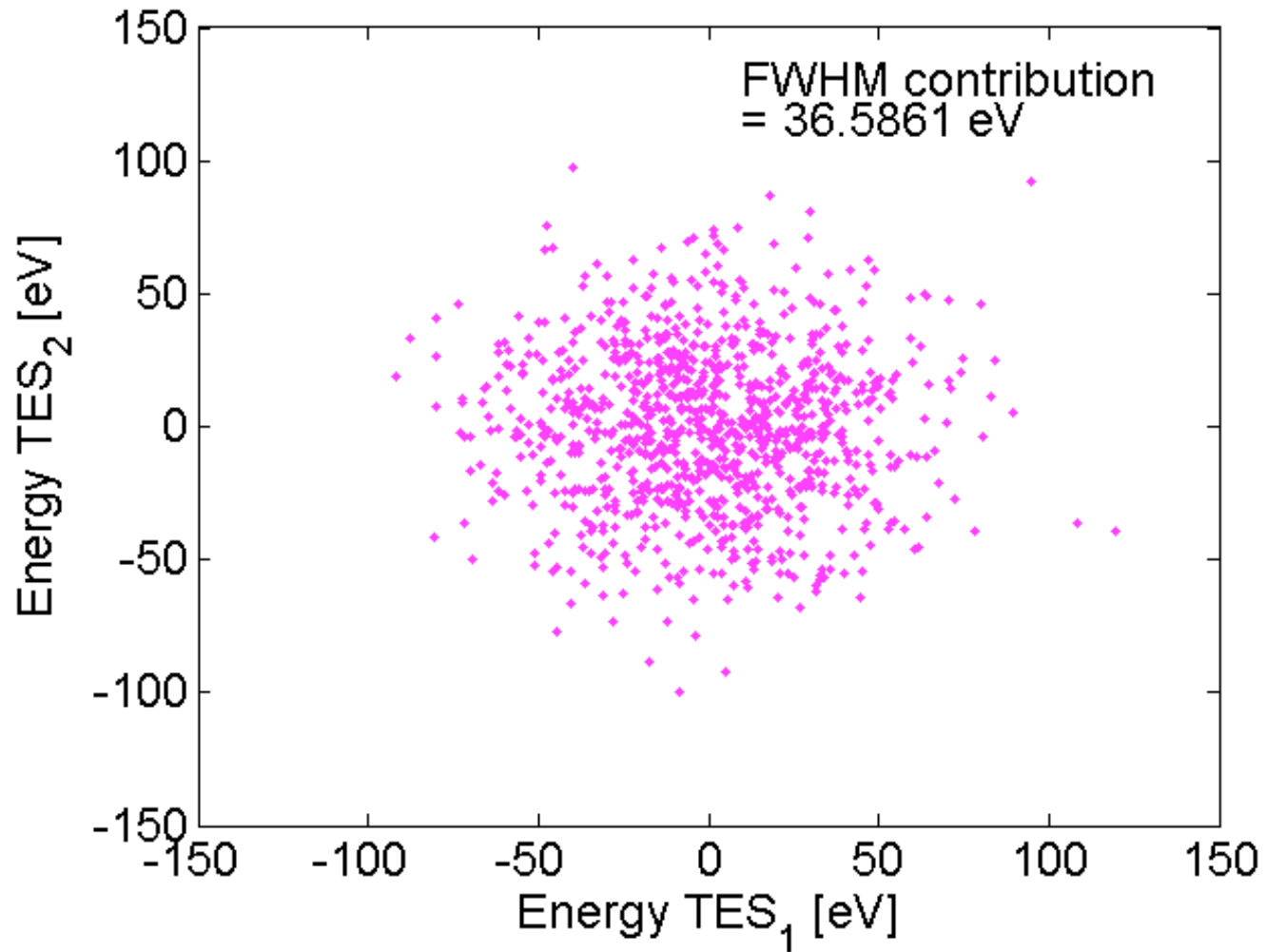




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# Noise FWHM Effect



# Fano Factor

$$\sigma = \sqrt{F \times E / \epsilon_0}$$

$$\sigma = \sqrt{0.08 \times 5900[\text{eV}] / 3.8[\text{eV}]}$$

- X-rays absorbed  $\rightarrow$  electron—hole pairs produced.
- Average 3.8eV of energy for their production.
- Their fluctuation however is no Poisson, but modified by the Fano factor.

# Phonons

$$\sigma = 1.2[\text{eV}] \times \sqrt{0.08 \times 5900[\text{eV}] / 3.8[\text{eV}]}$$

- These electron—hole pairs shed energy until they reach the velocity of sound.
- Their gap energy then dominates  $\sim 1.2\text{eV}$ .

# Full-Width at Half-Maximum

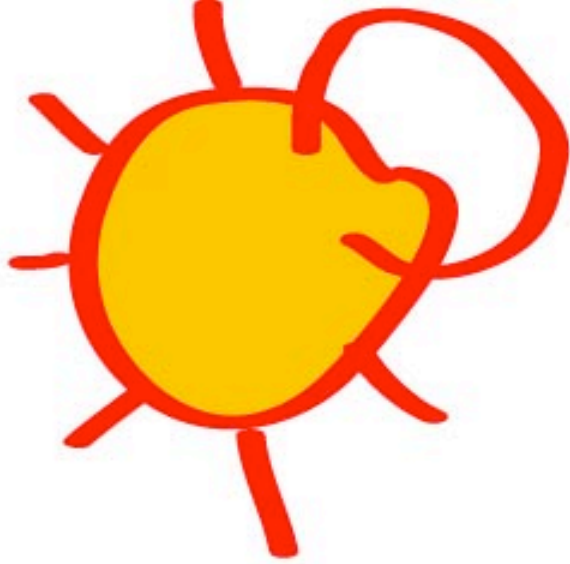
$$\begin{aligned}\Delta E_{FWHM} &= 2.355 \times 2 \times 1.2[\text{eV}] \times \sqrt{0.08 \times 5900[\text{eV}] / 3.8[\text{eV}]} \\ &= 63[\text{eV}]\end{aligned}$$

$$\sqrt{63^2 + 37^2} = 73 \approx 80$$

- ~2 calibration factor.
- 2.355 to convert to FWHM.
- 68% of energy initially goes into phonons. 76% could be absorbed in completely trenched TESs.
- Could this suggest the electron—hole pairs are not releasing their energy in the detector?

# Trap Concentrations

- Penn / Dougherty
  - 8,000  $\Omega$  cm
  - $10^{13}$  traps /  $\text{cm}^3$
- Us
  - 10  $\Omega$  cm
  - $10^{16}$  traps /  $\text{cm}^3$



**PHiMaTES**